

Data sheet acquired from Harris Semiconductor SCHS152D

September 1997 - Revised June 2004

High-Speed CMOS Logic 4- to 16-Line Decoder/Demultiplexer

Features

- Two Enable Inputs to Facilitate Demultiplexing and Cascading Functions
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, $I_I \le 1\mu A$ at V_{OL} , V_{OH}

Description

The 'HC154 and 'HCT154 are 4- to 16-line decoders/demultiplexers with two enable inputs, E1 and E2.

A High on either enable input forces the output into the High state. The demultiplexing function is performed by using the four input lines, A0 to A3, to select the output lines $\overline{Y0}$ to $\overline{Y15}$, and using one enable as the data input while holding the other enable low.

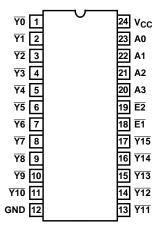
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC154F3A	-55 to 125	24 Ld CERDIP
CD54HCT154F3A	-55 to 125	24 Ld CERDIP
CD74HC154E	-55 to 125	24 Ld PDIP
CD74HC154EN	-55 to 125	24 Ld PDIP
CD74HC154M	-55 to 125	24 Ld SOIC
CD74HC154M96	-55 to 125	24 Ld SOIC
CD74HCT154E	-55 to 125	24 Ld PDIP
CD74HCT154EN	-55 to 125	24 Ld PDIP
CD74HCT154M	-55 to 125	24 Ld SOIC
CD74HCT154M96	-55 to 125	24 Ld SOIC

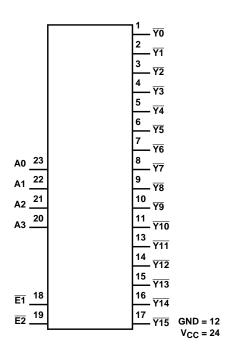
NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

Pinout

CD54HC154, CD54HCT154 (CERDIP) CD74HC154, CD74HCT154 (PDIP, SOIC) TOP VIEW



Functional Diagram



TRUTH TABLE

		INP	UTS										OUTI	PUTS							
E1	E2	А3	A2	A 1	Α0	<u>Y0</u>	<u>Y1</u>	<u>Y2</u>	<u></u> 73	<u>Y4</u>	<u>Y5</u>	<u>¥6</u>	<u>77</u>	<u>¥8</u>	<u>Y9</u>	<u>Y10</u>	<u>Y11</u>	<u>Y12</u>	<u>Y13</u>	<u>Y14</u>	<u>Y15</u>
L	L	L	L	L	L	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	L	L	Н	Н	L	Η	Η	Н	Η	Н	Н	Н	Н	Н	Ι	Η	Н	Η	Н
L	L	L	L	Н	L	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	L	Н	Н	Н	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	Н	L	L	Н	Н	Н	Н	L	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н
L	L	L	Н	L	Н	Н	Η	Η	Η	Н	L	Н	Н	Н	Н	Н	Ι	Η	Н	Η	Н
L	L	٦	Н	Ι	L	Η	Τ	Ι	Ι	Ι	Ι	L	Н	Η	Η	Н	Ι	Ι	Н	Ι	Н
L	L	٦	Н	Ι	Η	Η	Τ	Ι	Ι	Ι	Ι	Н	L	Η	Η	Н	Ι	Τ	Н	Ι	Н
L	L	Ι	L	L	L	Η	Τ	Ι	Ι	Ι	Ι	Н	Н	L	Η	Н	Ι	Τ	Н	Ι	Н
L	L	Ι	L	L	Η	Η	Τ	Ι	Ι	Ι	Ι	Н	Н	Η	L	Н	Ι	Τ	Н	Ι	Н
L	L	Η	L	Η	L	Ι	Ι	Ι	Ι	Η	Ι	Н	Н	Н	Η	L	Ι	Η	Н	Ι	Н
L	L	Η	L	Η	Η	Ι	Ι	Ι	Ι	Ι	Ι	Н	Н	Η	Η	Η	L	Η	Н	Ι	Н
L	L	Η	Ι	L	L	Ι	Ι	Ι	Ι	Η	Ι	Н	Н	Н	Η	Η	Ι	L	Н	Ι	Н
L	L	Η	Ι	L	Η	Ι	Ι	Ι	Ι	Η	Ι	Н	Н	Н	Η	Η	Ι	Η	L	Ι	Н
L	L	Η	Ι	Η	L	Ι	Ι	Ι	Ι	Η	Ι	Н	Н	Н	Η	Η	Ι	Η	Н	ا	Н
L	L	Н	Н	Η	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Η	Н	Н	Н	L
L	Н	Χ	Χ	Х	Χ	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Η	Н	Н	Н	Н
Н	L	Χ	Х	Х	Χ	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Η	Н	Н	Н	Н
Н	Н	Х	Χ	Х	Χ	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н	Н

H = High Voltage Level, L = Low Voltage Level, X = Don't Care

Thermal Information

Thermal Resistance (Typical)	θ _{JA} (ºC/W)
E (PDIP) Package (.600) (Note 1)	. 67
EN (PDIP) Package (.300) (Note 1)	. 67
M (SOIC) Package (Note 2)	. 46
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T _A)55°C to 125°C
Supply Voltage Range, V _{CC}
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V _I , V _O
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- 1. The package thermal impedance is calculated in accordance with JESD 51-3.
- 2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TES CONDI		V _{CC}		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	-l
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(S)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	ı	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	ı	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
Omeo Edudo			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	ı	-	3.84	-	3.7	-	V
			-5.2	6	5.48	ı	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	ı	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	ı	0.1	-	0.1	-	0.1	V
			0.02	6	-	ı	0.1	-	0.1	-	0.1	V
Low Level Output			-	i	-	ı	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	II	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	lcc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μА

DC Electrical Specifications (Continued)

		TES CONDI		V _{CC}		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES						-	-	-	-	-	-	
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	Voн	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V _{CC} and GND	0	5.5	-		±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 3)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
A0 - A3	1.4
<u>E1</u> , <u>E2</u>	1.3

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360µA max at $25^{o}C.$

Switching Specifications Input t_r , $t_f = 6ns$

		TEST		25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-								-		
Propagation Delay (Figure 1)	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
Address to Output			4.5	-	-	35	-	44	-	53	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns

^{3.} For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST			25°C		-40 ⁰ 85	C TO °C	-55°C T		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
E1 to Output	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	=	44	-	53	ns
		C _L =15pF	5	-	14	-	=	-	-	-	ns
		C _L = 50pF	6	-	-	30	=	37	-	45	ns
E2 to Output	t _{PLH} , t _{PHL}	C _L = 50pF	2	-	-	175	=	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C _{IN}	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	-	88	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay (Figure 2) Address to Output	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	35	-	44	-	53	ns
		C _L =15pF	5	-	14	-	-		-	-	ns
E1 to Output	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-	-	34	-	43	-	51	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
E2 to Output	t _{PLH} , t _{PHL}	C _L = 50pF	4.5	-		34	-	43	-	51	ns
		C _L =15pF	5	-	14	-	-	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C _{IN}	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5		84	-	-	-	-	-	pF

NOTES:

^{4.} $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per gate.

^{5.} $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = input frequency, C_L = output load capacitance, V_{CC} = supply voltage.

Test Circuits and Waveforms

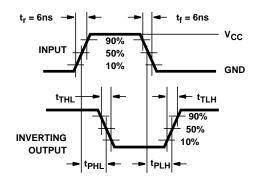


FIGURE 1. HC AND HCU TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

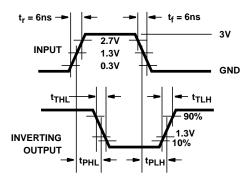


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC





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PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8670101JA	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8670101JA CD54HCT154F3A	Sample
5962-8682201JA	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8682201JA CD54HC154F3A	Samples
CD54HC154F3A	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8682201JA CD54HC154F3A	Samples
CD54HCT154F3A	ACTIVE	CDIP	J	24	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-8670101JA CD54HCT154F3A	Samples
CD74HC154E	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC154E	Samples
CD74HC154EE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC154E	Samples
CD74HC154EN	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC154EN	Samples
CD74HC154ENE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC154EN	Samples
CD74HC154M	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154M96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154M96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154M96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154ME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HC154MG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC154M	Samples
CD74HCT154E	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT154E	Samples
CD74HCT154EE4	ACTIVE	PDIP	N	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT154E	Samples
CD74HCT154EN	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT154EN	Samples



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PACKAGE OPTION ADDENDUM

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Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CD74HCT154ENE4	ACTIVE	PDIP	NT	24	15	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT154EN	Samples
CD74HCT154M	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154M96	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154M96E4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154M96G4	ACTIVE	SOIC	DW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154ME4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples
CD74HCT154MG4	ACTIVE	SOIC	DW	24	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT154M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.



PACKAGE OPTION ADDENDUM

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(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD54HC154, CD54HCT154, CD74HC154, CD74HCT154:

Catalog: CD74HC154, CD74HCT154

Military: CD54HC154, CD54HCT154

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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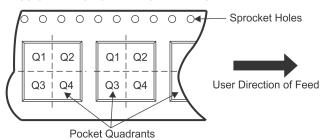
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
BO	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC154M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HC154M96G4	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HCT154M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

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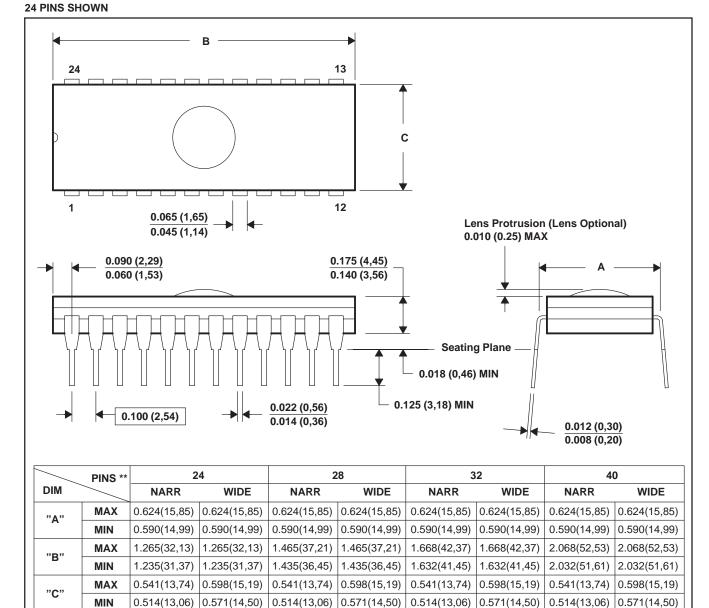
*All dimensions are nominal

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	Device	Package Type	Package Drawing	Pins SPQ		Length (mm)	Width (mm)	Height (mm)	
	CD74HC154M96	SOIC	DW	24	2000	366.0	364.0	50.0	
	CD74HC154M96G4	SOIC	DW	24	2000	367.0	367.0	45.0	
	CD74HCT154M96	SOIC	DW	24	2000	367.0	367.0	45.0	

4040084/C 10/97

J (R-GDIP-T**)

CERAMIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

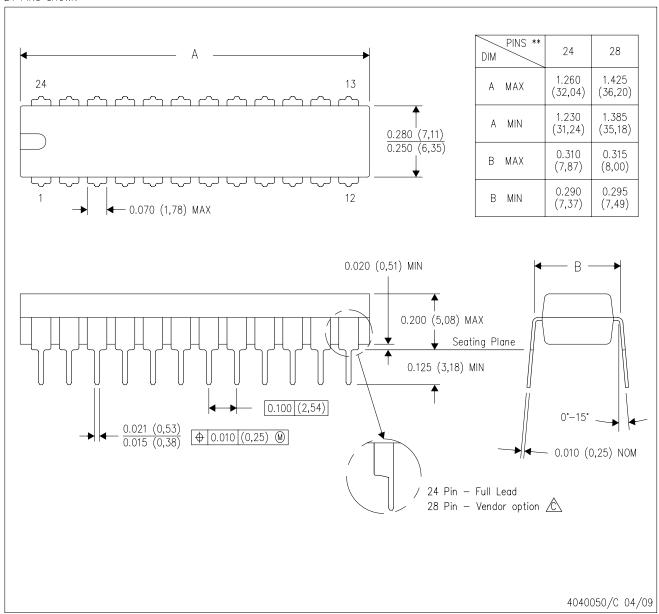
- B. This drawing is subject to change without notice.
- C. Window (lens) added to this group of packages (24-, 28-, 32-, 40-pin).
- D. This package can be hermetically sealed with a ceramic lid using glass frit.
- E. Index point is provided on cap for terminal identification.



NT (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

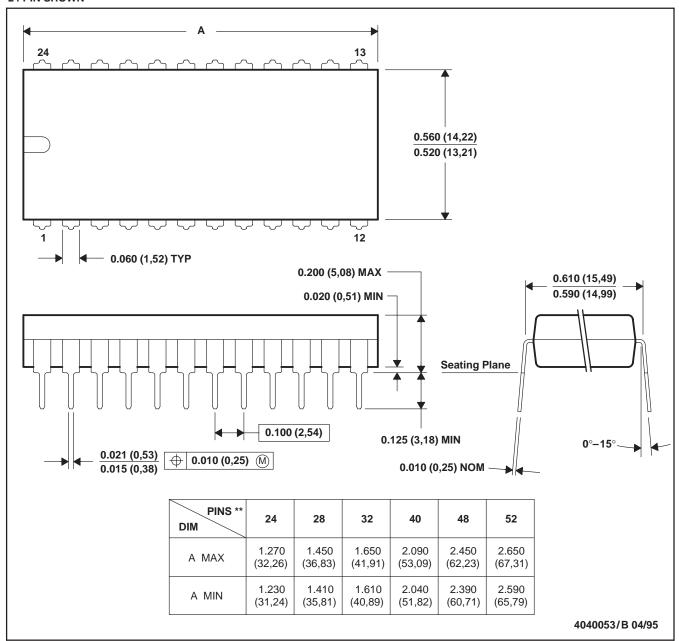
The 28 pin end lead shoulder width is a vendor option, either half or full width.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

24 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-011
- D. Falls within JEDEC MS-015 (32 pin only)



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



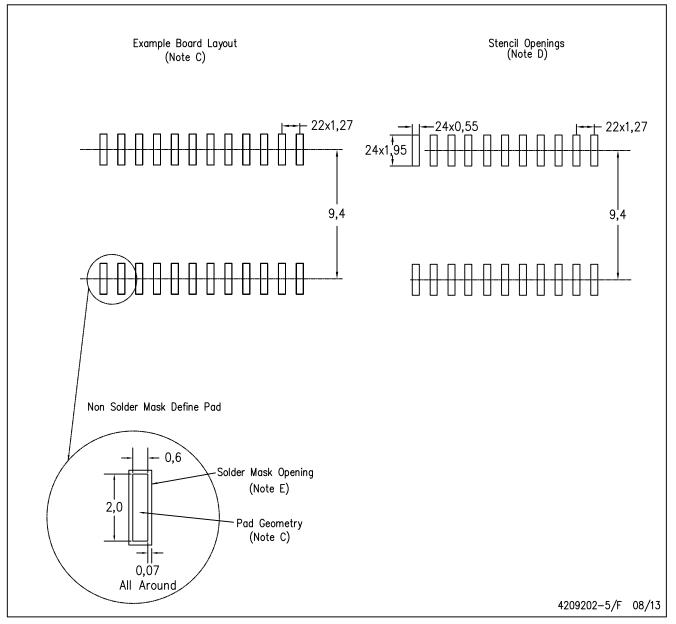
NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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